# NSR02100HT1G

# **Schottky Barrier Diodes**

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

#### Features

- Fast Switching Speed
- Low Leakage Current
- Low Forward Voltage 0.45 V @  $I_F = 1$  mAdc
- Surface Mount Device
- Low Capacitance Diode
- NSVR Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit
Total Device Dissipation FR–5 Board, (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>D</sub>	200 1.57	mW mW/°C
Forward Current (DC)	١ <sub>F</sub>	200	mA
Non–Repetitive Peak Forward Current, $t_p < 10$ msec	I <sub>FSM</sub>	2	А
Thermal Resistance Junction-to-Ambient	$R_{\thetaJA}$	635	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. FR-4 Minimum Pad



## **ON Semiconductor®**

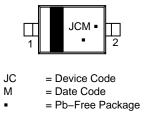
www.onsemi.com

## 100 VOLT SCHOTTKY BARRIER DIODE





### MARKING DIAGRAM



(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSR02100HT1G	SOD-323 (Pb-Free)	3,000 / Tape & Reel
NSVR02100HT1G	SOD-323 (Pb-Free)	3,000 / Tape & Reel

<sup>+</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## NSR02100HT1G

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage $(I_R = 10 \ \mu A)$	V <sub>R</sub>	-	100	-	V
Reverse Leakage $(V_R = 50 \text{ V})$	۱ <sub>R</sub>	_	_	0.05	μAdc
Reverse Leakage (V <sub>R</sub> = 100 V)	I <sub>R</sub>	_	_	0.15	μAdc
Forward Voltage (I <sub>F</sub> = 1 mAdc)	V <sub>F</sub>	_	_	0.45	Vdc
Forward Voltage (I <sub>F</sub> = 10 mAdc)	V <sub>F</sub>	_	_	0.57	Vdc
Forward Voltage (I <sub>F</sub> = 100 mAdc)	V <sub>F</sub>	_	_	0.80	Vdc
Forward Voltage (I <sub>F</sub> = 200 mAdc)	V <sub>F</sub>	_	_	0.95	Vdc
Total Capacitance $(V_R = 1.0 \text{ V}, f = 1.0 \text{ MHz})$	C <sub>T</sub>	_	4	10	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## NSR02100HT1G

### **TYPICAL CHARACTERISTICS**

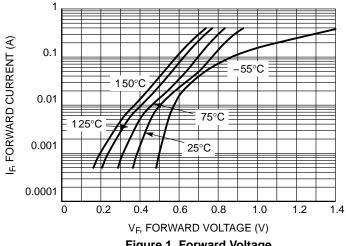
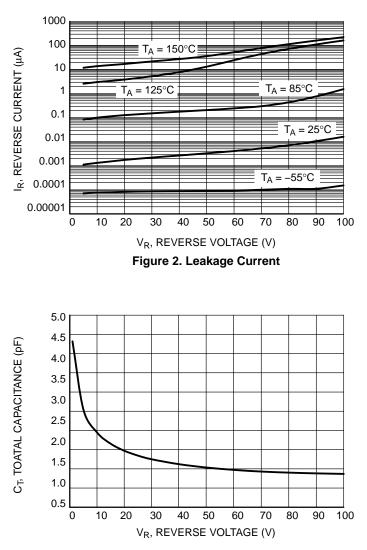


Figure 1. Forward Voltage

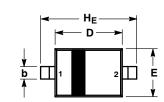


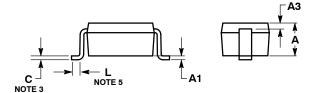












#### **SOLDERING FOOTPRINT\***



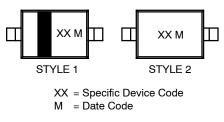
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DATE 13 MAR 2007

- NOTES:
  DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETERS.
  LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
  DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
С	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
Е	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
HE	2.30	2.50	2.70	0.090	0.098	0.105

#### GENERIC **MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present.

STYLE 1: PIN 1. CATHODE (POLARITY BAND) 2. ANODE STYLE 2: NO POLARITY

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SOD-323 CASE 477-02

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